

PJS6403-AU

30V P-Channel Enhancement Mode MOSFET

Voltage	-30 V	Current	-6.4A
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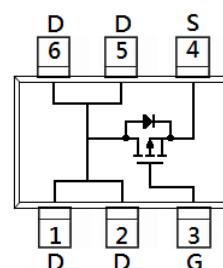
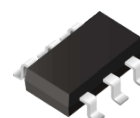
Features

- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-4A < 32m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-2A < 46m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-23 6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0005 ounces, 0.0142 grams

SOT-23 6L



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-30	V
Gate-Source Voltage		V _{GS}	±20	
Continuous Drain Current ^(Note 4)		I _D	-6.4	A
Pulsed Drain Current ^(Note 1)		I _{DM}	-25.6	
Power Dissipation	T _a =25°C	P _D	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55~150	°C
Typical Thermal Resistance		R _{θJA}	62.5	°C/W
- Junction to Ambient ^(Note 4,5)				



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Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.6	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-4A	-	27	32	mΩ
		V _{GS} =-4.5V, I _D =-2A	-	38	46	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =+20V, V _{DS} =0V	-	-	+100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =-15V, I _D =-5A, V _{GS} =-4.5V ^(Note 2,3)	-	7.8	-	nC
Gate-Source Charge	Q _{gs}		-	2.7	-	
Gate-Drain Charge	Q _{gd}		-	2.8	-	
Input Capacitance	C _{iss}	V _{DS} =-15V, V _{GS} =0V, f=1MHZ	-	870	-	pF
Output Capacitance	C _{oss}		-	130	-	
Reverse Transfer Capacitance	C _{rss}		-	93	-	
Turn-On Delay Time	td _(on)	V _{DD} =-15V, I _D =-1A, V _{GS} =-10V, R _G =6Ω ^(Note 2,3)	-	6.5	-	ns
Turn-On Rise Time	tr		-	8.8	-	
Turn-Off Delay Time	td _(off)		-	73	-	
Turn-Off Fall Time	tf		-	44	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	-2	A
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.75	-1	V

NOTES :

- Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.
- Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^{\circ}\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^{\circ}\text{C}$.
- The maximum current rating is package limited.
- $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- Guaranteed by design, not subject to production testing

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TYPICAL CHARACTERISTIC CURVES

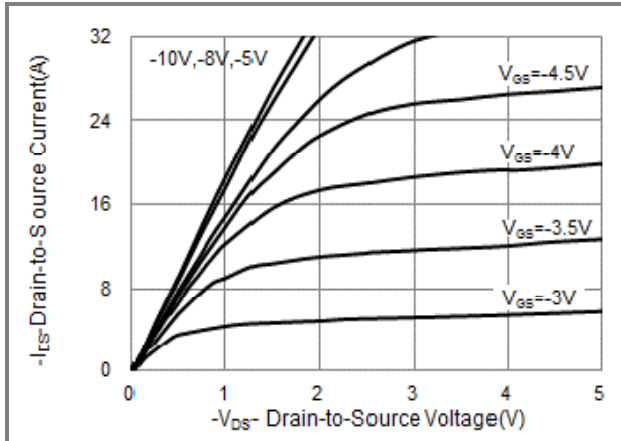


Fig.1 On-Region Characteristics

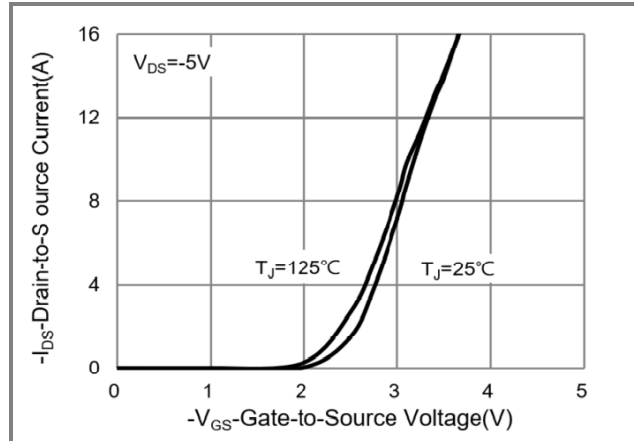


Fig.2 Transfer Characteristics

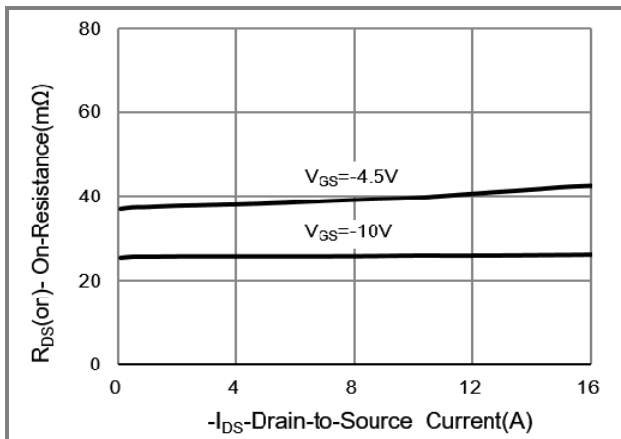


Fig.3 On-Resistance vs. Drain Current

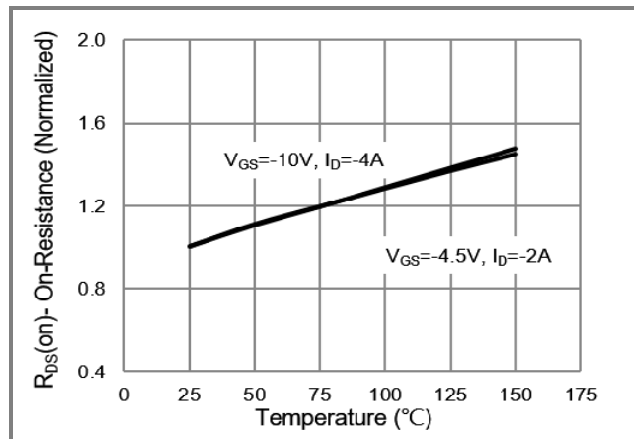


Fig.4 On-Resistance vs. Junction temperature

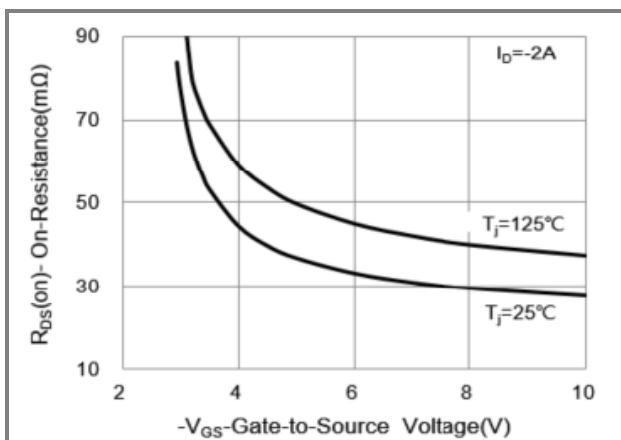


Fig.5 On-Resistance Variation with V_{GS}

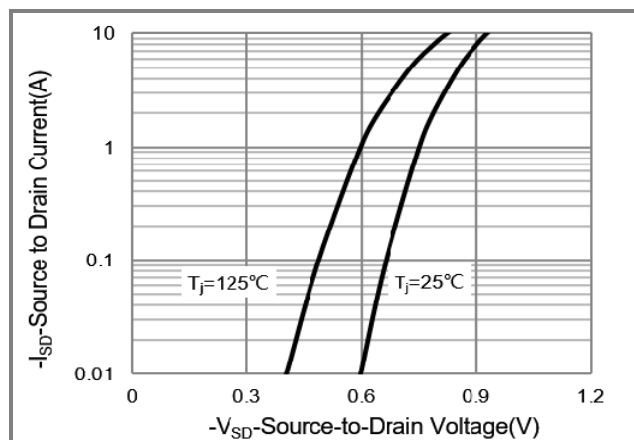


Fig.6 Body Diode Characteristics



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TYPICAL CHARACTERISTIC CURVES

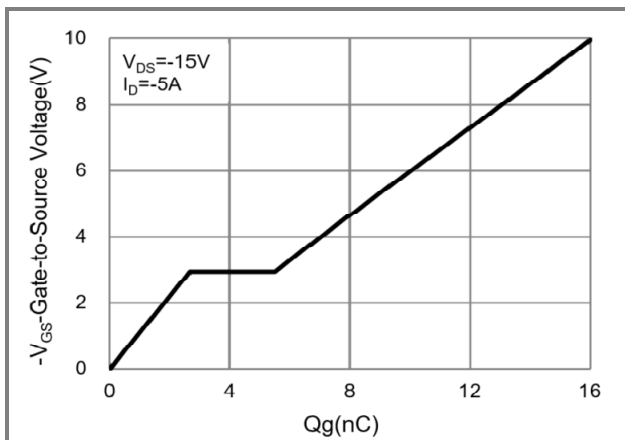


Fig.7 Gate-Charge Characteristics

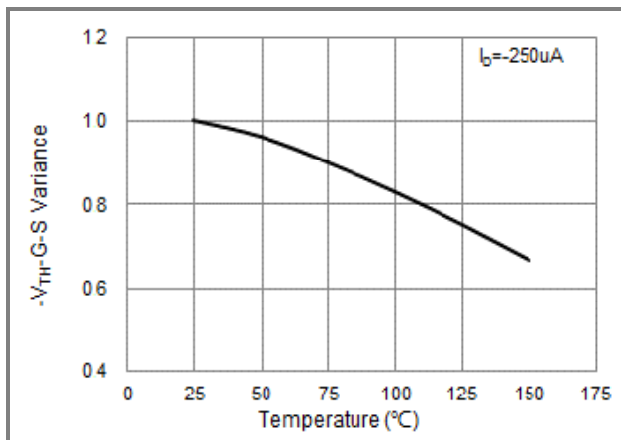


Fig.8 Threshold Voltage Variation with Temperature

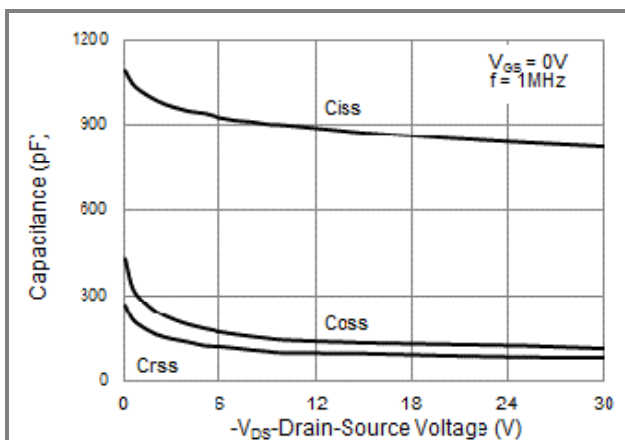


Fig.9 Capacitance vs. Drain-Source Voltage

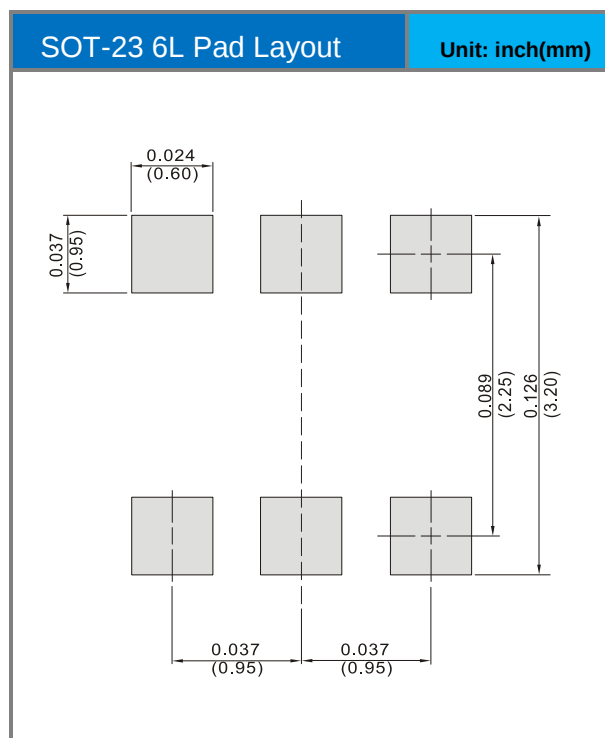
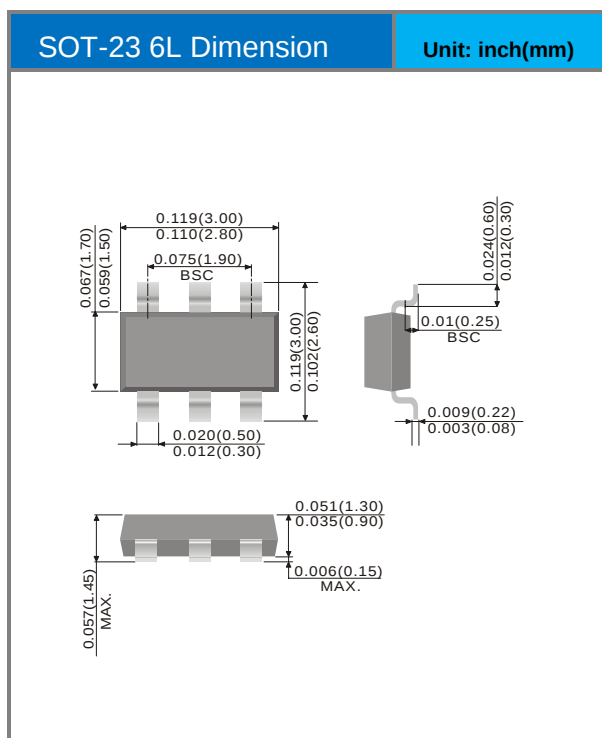


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Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6403-AU_S1_000A1	SOT-23 6L	3K pcs / 7" reel	S03	Halogen free

Packaging Information & Mounting Pad Layout





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